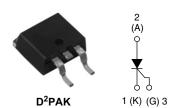




Vishay High Power Products

Surface Mountable

Phase Control SCR, 10 A



PRODUCT SUMMARY		
V _T at 6.5 A	< 1.15 V	
I _{TSM}	140 A	
V_{RRM}	800 V	

DESCRIPTION/FEATURES

The 10TTS08S High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS					
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper	2.5	3.5			
Aluminum IMS, R _{thCA} = 15 °C/W	6.3	9.5	A		
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	14.0	18.5			

[•] $T_A = 55$ °C, $T_J = 125$ °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{T(AV)}	Sinusoidal waveform	6.5	A	
I _{RMS}		10	A	
V _{RRM} /V _{DRM}		800	V	
I _{TSM}		140	A	
V _T	6.5 A, T _J = 25 °C	1.15	V	
dV/dt		150	V/µs	
dl/dt		100	A/μs	
TJ	Range	- 40 to 125	°C	

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
10TTS08S	800	800	1.0

Document Number: 93691 Revision: 19-Jun-08

Vishay High Power Products

Surface Mountable Phase Control SCR, 10 A



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 112 °C, 180° conduction half sine wave		6.5	
Maximum RMS on-state current	I _{T(RMS)}	1C = 112 C, 160 CONUL	iction half sine wave	10	^
Maximum peak, one-cycle,	1	10 ms sine pulse, rated	V _{RRM} applied, T _J = 125 °C	120	Α
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volt	age reapplied, T _J = 125 °C	140	
Maximum 12t fax fusing	l²t	10 ms sine pulse, rated	V _{RRM} applied, T _J = 125 °C	72	A ² s
Maximum I ² t for fusing	I-I	10 ms sine pulse, no voltage re		100	A-S
Maximum I ² √t for fusing	I ² √t	$t = 0.1$ to 10 ms, no voltage reapplied, $T_J = 125$ °C		1000	A²√s
Maximum on-state voltage drop	V_{TM}	6.5 A, T _J = 25 °C		1.15	V
On-state slope resistance	r _t	T _J = 125 °C		17.3	mΩ
Threshold voltage	V _{T(TO)}			0.85	V
Maximum reverse and direct lookage current	1 /1	T _J = 25 °C	V - Poted V /V	0.05	
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C	$V_R = Rated V_{RRM}/V_{DRM}$	1.0	
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial $I_T = 1 \text{ A}$		30	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load		50	
Maximum rate of rise of off-state voltage	dV/dt	T _J = 25 °C		150	V/µs
Maximum rate of rise of turned-on current	dl/dt			100	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	w
Maximum average gate power	P _{G(AV)}		2.0	VV
Maximum peak positive gate current	+I _{GM}		1.5	Α
Maximum peak negative gate voltage	-V _{GM}		10	V
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA
		Anode supply = 6 V, resistive load, T _J = 25 °C	15	
		Anode supply = 6 V, resistive load, T _J = 125 °C	10	
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2	
		Anode supply = 6 V, resistive load, T _J = 25 °C	1	v
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 125 °C, V _{DRM} = Rated value 0.2 0.1		
Maximum DC gate current not to trigger	I _{GD}			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8	
Typical reverse recovery time	t _{rr}	T _{.I} = 125 °C	3	μs
Typical turn-off time	tq	1J = 125 C	100	

Document Number: 93691

Revision: 19-Jun-08



Surface Mountable Phase Control SCR, 10 A

Vishay High Power Products

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C
Soldering temperature	T _S	For 10 s (1.6 mm from case)	240	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	O/VV
Approximate weight			2	g
Approximate weight			0.07	oz.
Marking device		Case style D ² PAK (SMD-220)	10TTS	08S

Note

Document Number: 93691 Revision: 19-Jun-08

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

Vishay High Power Products

Surface Mountable Phase Control SCR, 10 A



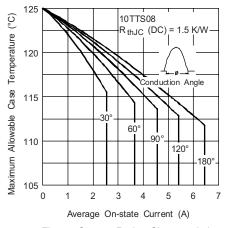


Fig. 1 - Current Rating Characteristics

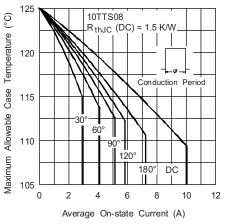


Fig. 2 - Current Rating Characteristics

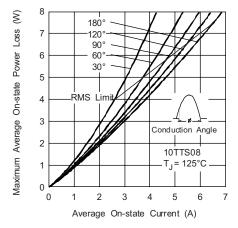


Fig. 3 - On-State Power Loss Characteristics

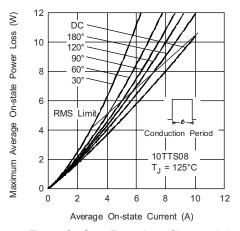


Fig. 4 - On-State Power Loss Characteristics

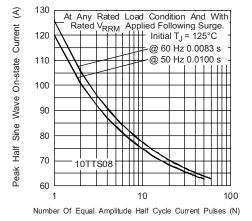


Fig. 5 - Maximum Non-Repetitive Surge Current

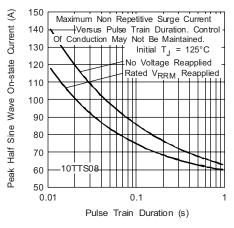


Fig. 6 - Maximum Non-Repetitive Surge Current

Revision: 19-Jun-08



Surface Mountable Phase Control SCR, 10 A Vishay High Power Products

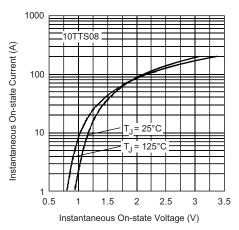


Fig. 7 - On-State Voltage Drop Characteristics

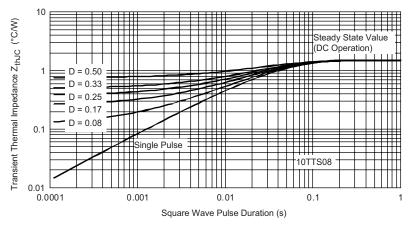


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

Document Number: 93691 Revision: 19-Jun-08

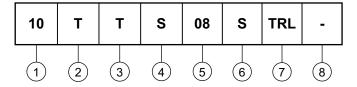
Vishay High Power Products

Surface Mountable Phase Control SCR, 10 A



ORDERING INFORMATION TABLE

Device code



- 1 Current rating, RMS value
- 2 Circuit configuration:

T = Single thyristor

- 3 Package:
 - T = TO-220AC
- 4 Type of silicon:
 - S = Converter grade
- 5 Voltage code x 100 = V_{RRM}
 - $S = TO-220 D^2PAK (SMD-220) version$
- 7 Tape and reel option:
 - TRL = Left reel
 - TRR = Right orientation reel
- 8 • None = Standard production
 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95046			
Part marking information	http://www.vishay.com/doc?95054		
Packaging information	http://www.vishay.com/doc?95032		

www.vishay.com

For technical questions, contact: diodes-tech@vishay.com

Document Number: 93691 Revision: 19-Jun-08

Downloaded from Elcodis.com electronic components distributor





Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com